



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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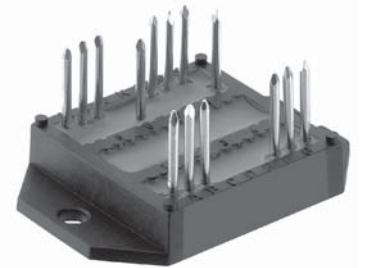
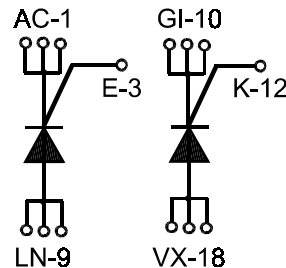
Thyristor Modules

ECO-PAC 2

$I_{TRMS} = 2 \times 180A$
 $I_{TAVM} = 2 \times 105A$
 $V_{RRM} = 800-1800 V$

Preliminary Data

| V_{RSM} V_{DSM} V | V_{RRM} V_{DRM} V | Typ |
|-----------------------------|-----------------------------|-------------------|
| 900 | 800 | VCC 2x105 - 08io7 |
| 1300 | 1200 | VCC 2x105 - 12io7 |
| 1500 | 1400 | VCC 2x105 - 14io7 |
| 1700 | 1600 | VCC 2x105 - 16io7 |
| 1900 | 1800 | VCC 2x105 - 18io7 |



| Symbol | Conditions | Maximum Ratings | | |
|----------------|---|----------------------------------|------------------|------------|
| I_{TRMS} | | 180 | A | |
| I_{TAVM} | $T_C = 85^\circ C$; 180° sine | 105 | A | |
| I_{TSM} | $T_{VJ} = 45^\circ C$; $V_R = 0 V$; t = 10 ms (50 Hz), sine | 2250 | A | |
| | t = 8.3 ms (60 Hz), sine | 2400 | A | |
| I^2dt | $T_{VJ} = 125^\circ C$; $V_R = 0 V$; t = 10 ms (50 Hz), sine | 2000 | A | |
| | t = 8.3 ms (60 Hz), sine | 2150 | A | |
| I^2dt | $T_{VJ} = 45^\circ C$; $V_R = 0 V$; t = 10 ms (50 Hz), sine | 25300 | A ² s | |
| | t = 8.3 ms (60 Hz), sine | 23900 | A ² s | |
| I^2dt | $T_{VJ} = 125^\circ C$; $V_R = 0 V$; t = 10 ms (50 Hz), sine | 20000 | A ² s | |
| | t = 8.3 ms (60 Hz), sine | 19100 | A ² s | |
| $(di/dt)_{cr}$ | $T_{VJ} = 125^\circ C$; f = 50 Hz; $t_p = 200 \mu s$; $V_D = \frac{2}{3} V_{DRM}$; $I_G = 0.45 A$ | repetitive, $I_T = 250 A$ | 150 | A/ μs |
| | $di_G/dt = 0.45 A/\mu s$; | non repetitive, $I_T = I_{TAVM}$ | 500 | A/ μs |
| $(dv/dt)_{cr}$ | $T_{VJ} = 125^\circ C$; $V_{DR} = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$, method 1 (linear voltage rise) | | 1000 | V/ μs |
| P_{GM} | $T_{VJ} = 125^\circ C$; | $t_p = 30 ms$ | ≤ 10 | W |
| | $I_T = I_{TAVM}$; | $t_p = 300 ms$ | ≤ 5 | W |
| P_{GAVM} | | | 0.5 | W |
| V_{RGM} | | | 10 | V |
| T_{VJ} | | | -40 ... + 125 | °C |
| T_{VJM} | | | 125 | °C |
| T_{stg} | | | -40 ... + 125 | °C |
| V_{ISOL} | 50/60 Hz, RMS | t = 1 min | 3000 | V ~ |
| | $I_{ISOL} \leq 1 mA$ | t = 1 s | 3600 | V ~ |
| M_d | Mounting torque (M4) | | 1.5 - 2.0 | Nm |
| | | | 14 - 18 | lb.in. |
| Weight | typ. | | 26 | g |

Features

- Isolation voltage 3600 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

Applications

- DC motor control
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling
- High power density
- Small and light weight

Data according to IEC 60747 refer to a single thyristor unless otherwise stated
 IXYS reserves the right to change limits, test conditions and dimensions.

| Component | | Characteristic Values | | |
|------------|---|-----------------------|------------|----------------------|
| Symbol | Conditions | min. | typ. | max. |
| I_D, I_R | $T_{VJ} = 125^\circ\text{C}; V_R = V_{RRM}; V_D = V_{DRM}$ | | | 5 mA |
| V_T | $I_T = 300\text{ A}; T_{VJ} = 25^\circ\text{C}$ | | | 1.5 V |
| V_{TO} | For power-loss calculations only | | | 0.8 V |
| r_T | | | | 2.4 mΩ |
| V_{GT} | $V_D = 6\text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$ | | | 1.5 V 1.6 V |
| I_{GT} | $V_D = 6\text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$ | | | 150 mA 200 mA |
| V_{GD} | $T_{VJ} = 125^\circ\text{C}; V_D = \frac{2}{3}V_{DRM}$ | | | 0.2 V |
| I_{GD} | $T_{VJ} = 125^\circ\text{C}; V_D = \frac{2}{3}V_{DRM}$ | | | 10 mA |
| I_L | $T_{VJ} = 25^\circ\text{C}; t_p = 10\text{ ms}$ $I_G = 0.45\text{ A}; di_G/dt = 0.45\text{ A}/\mu\text{s}$ | | | 450 mA |
| I_H | $T_{VJ} = 25^\circ\text{C}; V_D = 6\text{ V}; R_{GK} = \infty$ | | | 200 mA |
| t_{gd} | $T_{VJ} = 25^\circ\text{C}; V_D = \frac{1}{2}V_{DRM}$ $I_G = 0.45\text{ A}; di_G/dt = 0.45\text{ A}/\mu\text{s}$ | | | 2 μs |
| R_{thJC} | per Thyristor; DC per module | | | 0.26 K/W 0.13 K/W |
| R_{thCH} | per Thyristor; DC per module | | 0,2 0,1 | K/W K/W |
| d_s | Creeping distance on surface | | | 11.2 mm |
| d_A | Creeping distance in air | | | 5.0 mm |
| a | Max. allowable acceleration | | | 50 m/s ² |

